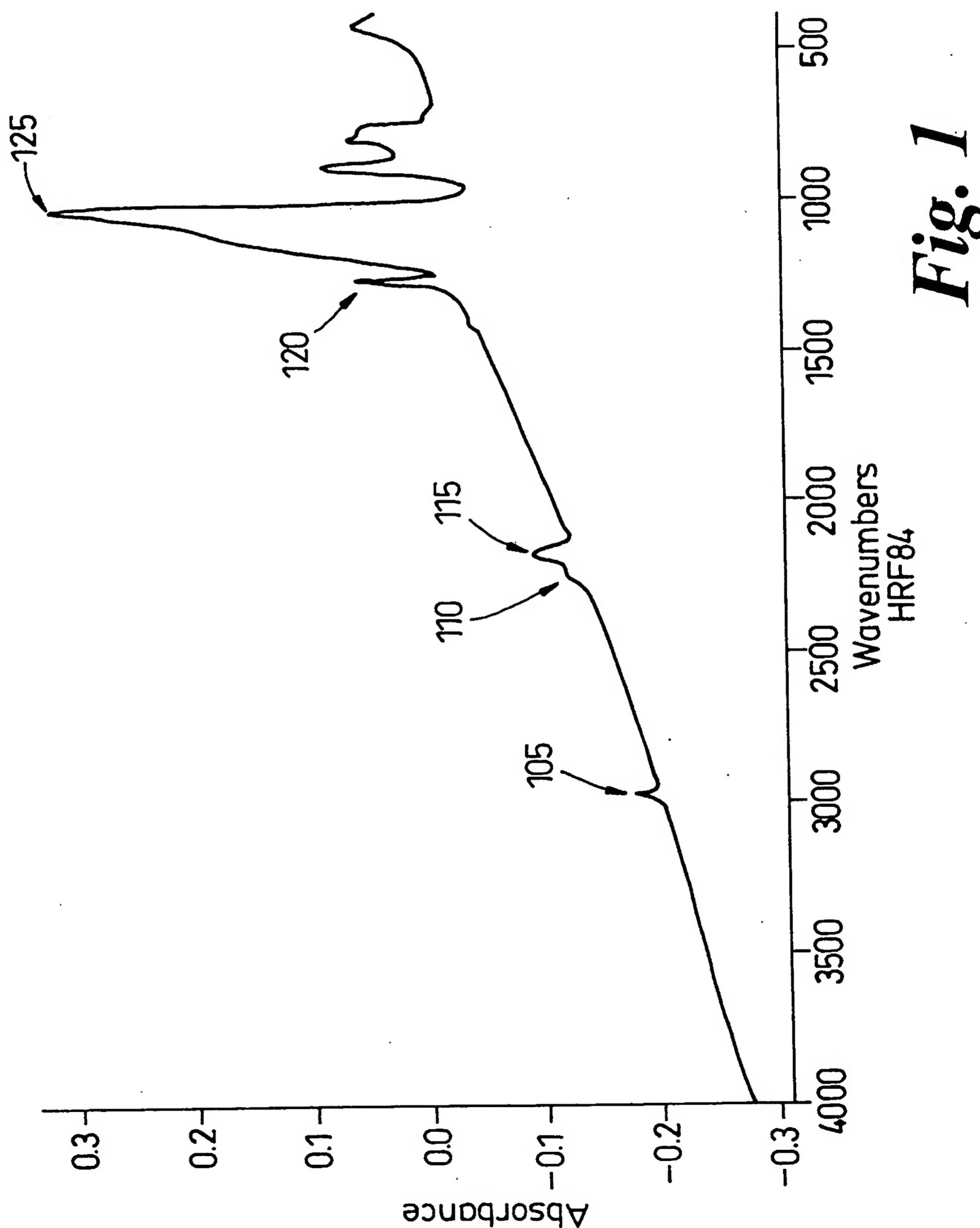
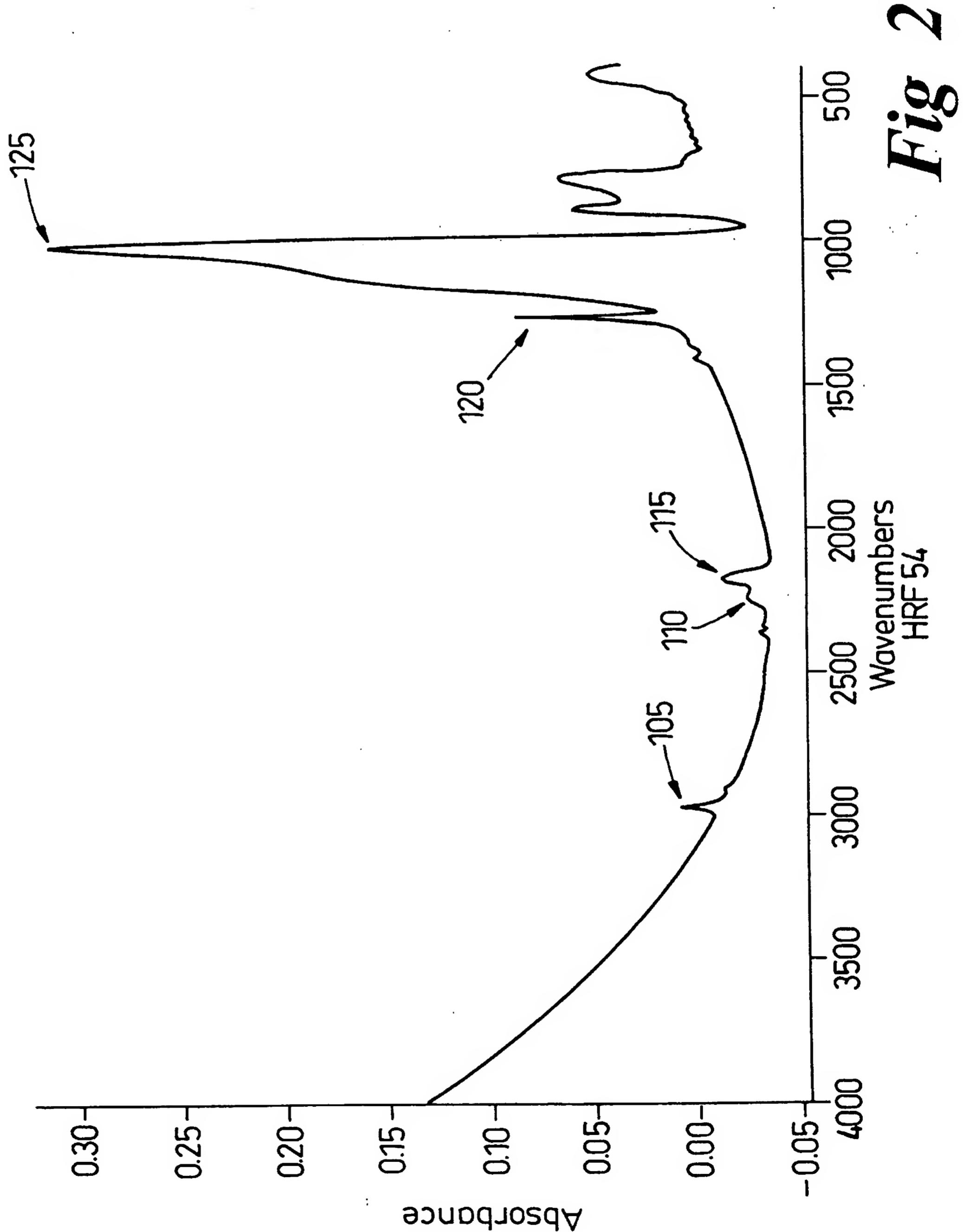


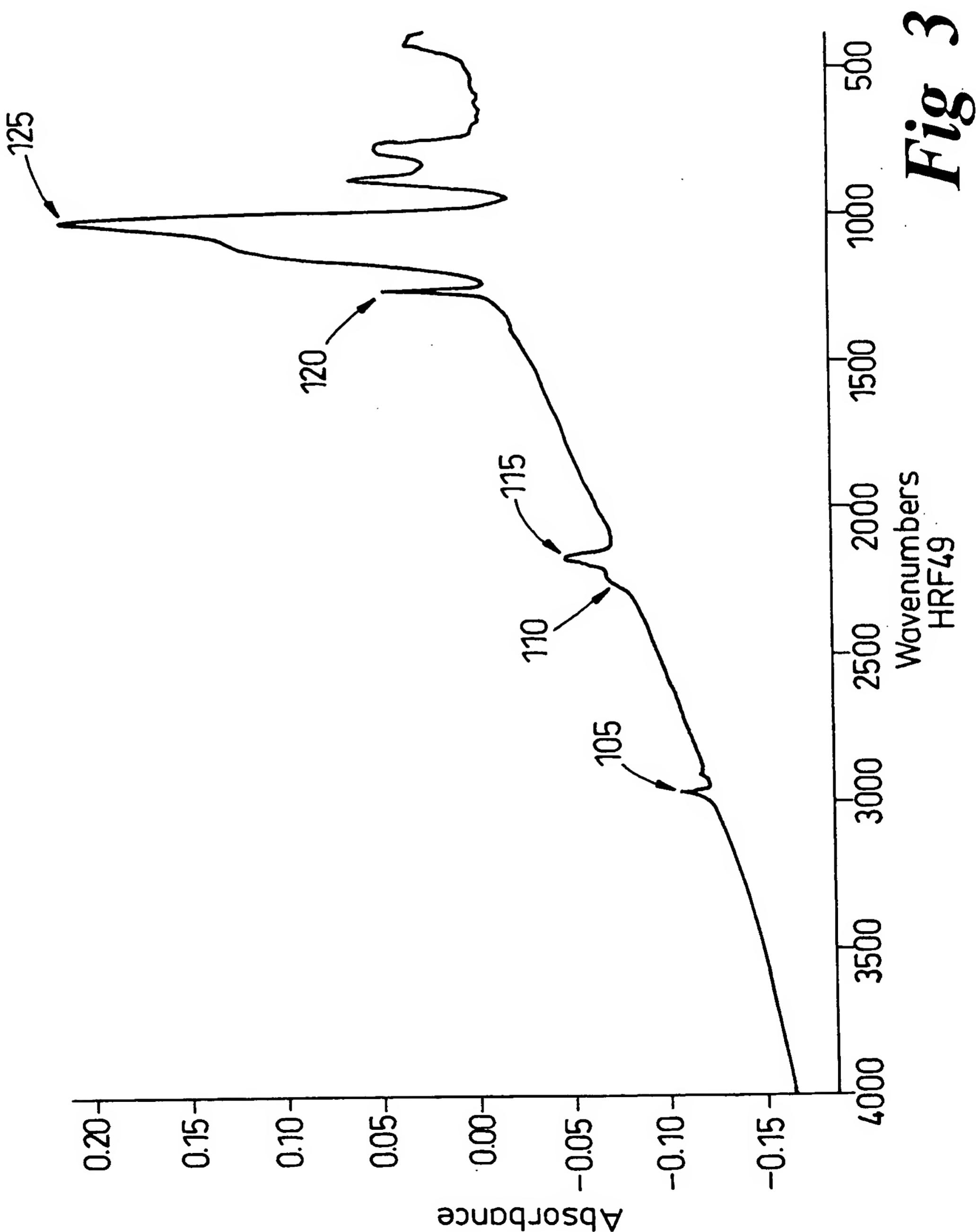
"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



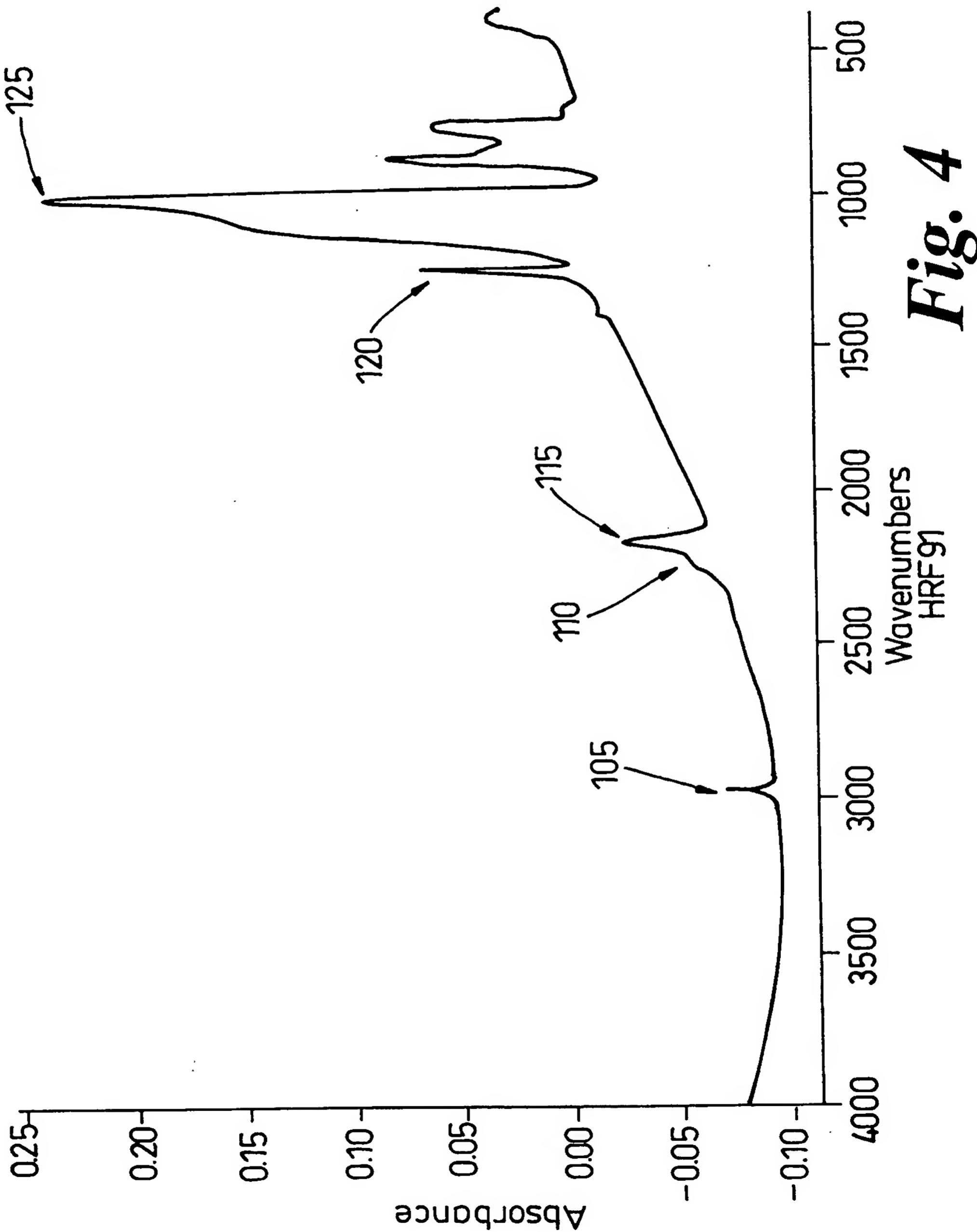
"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL

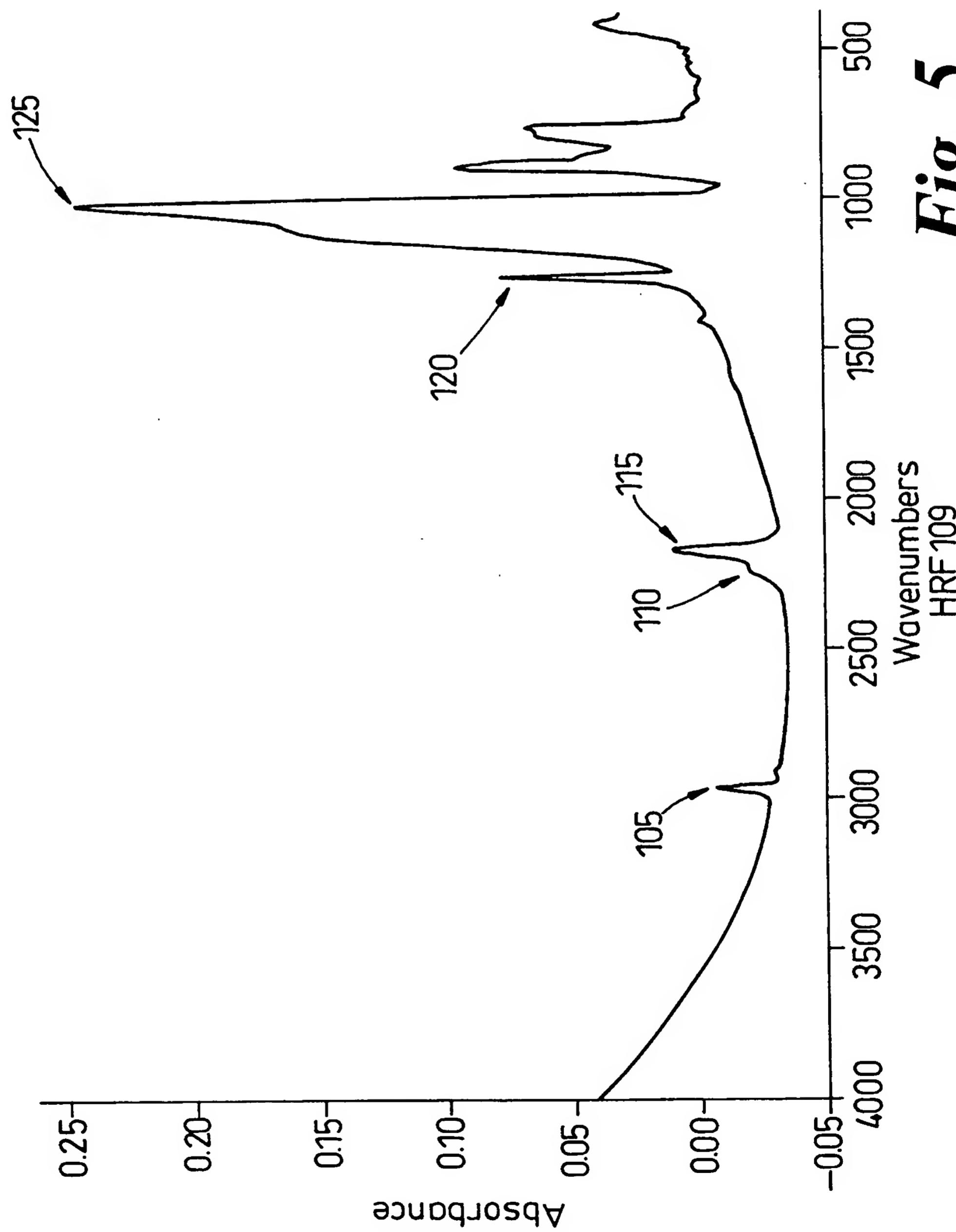


Fig. 5

"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL

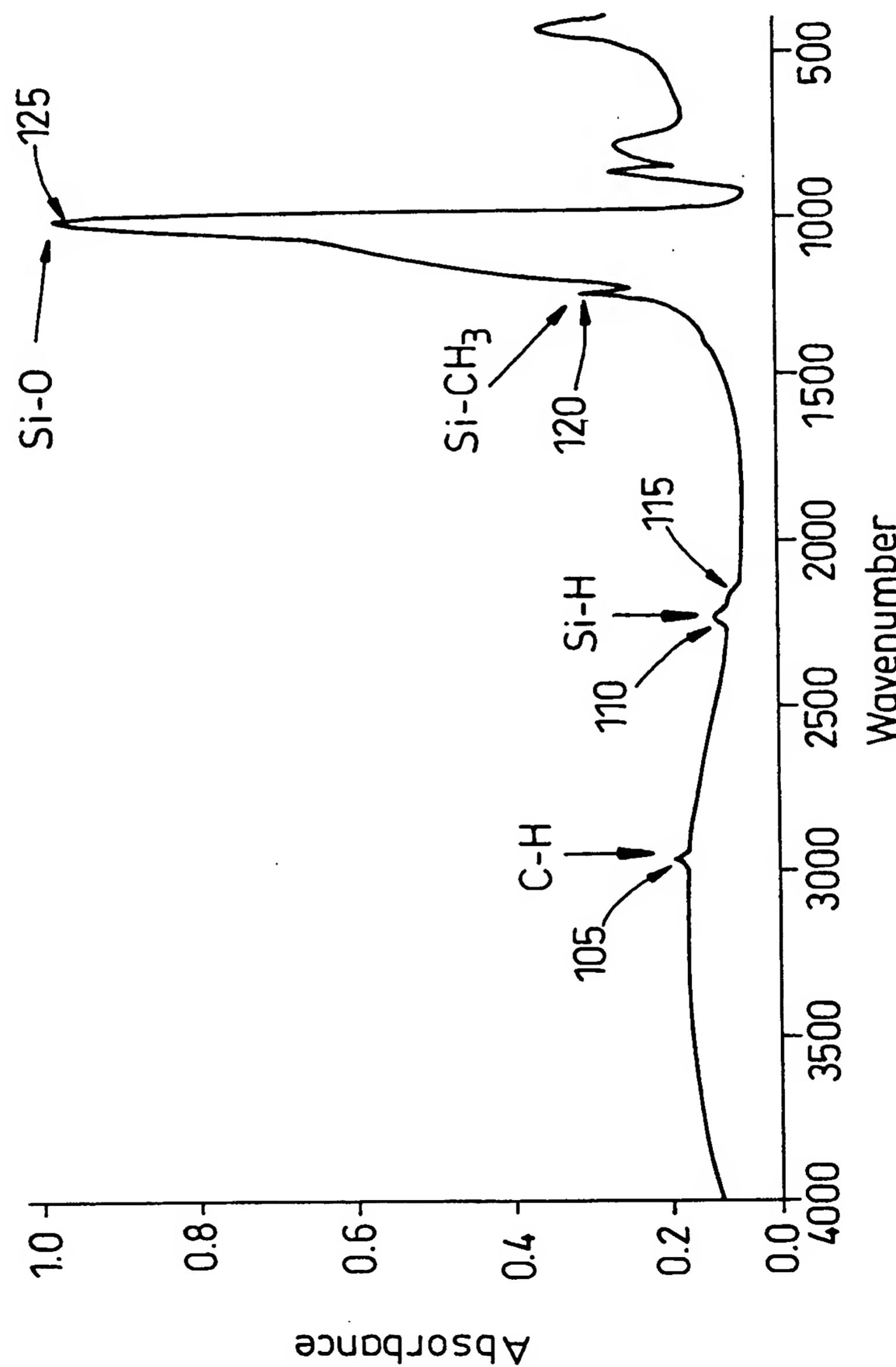


Fig. 6

"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL

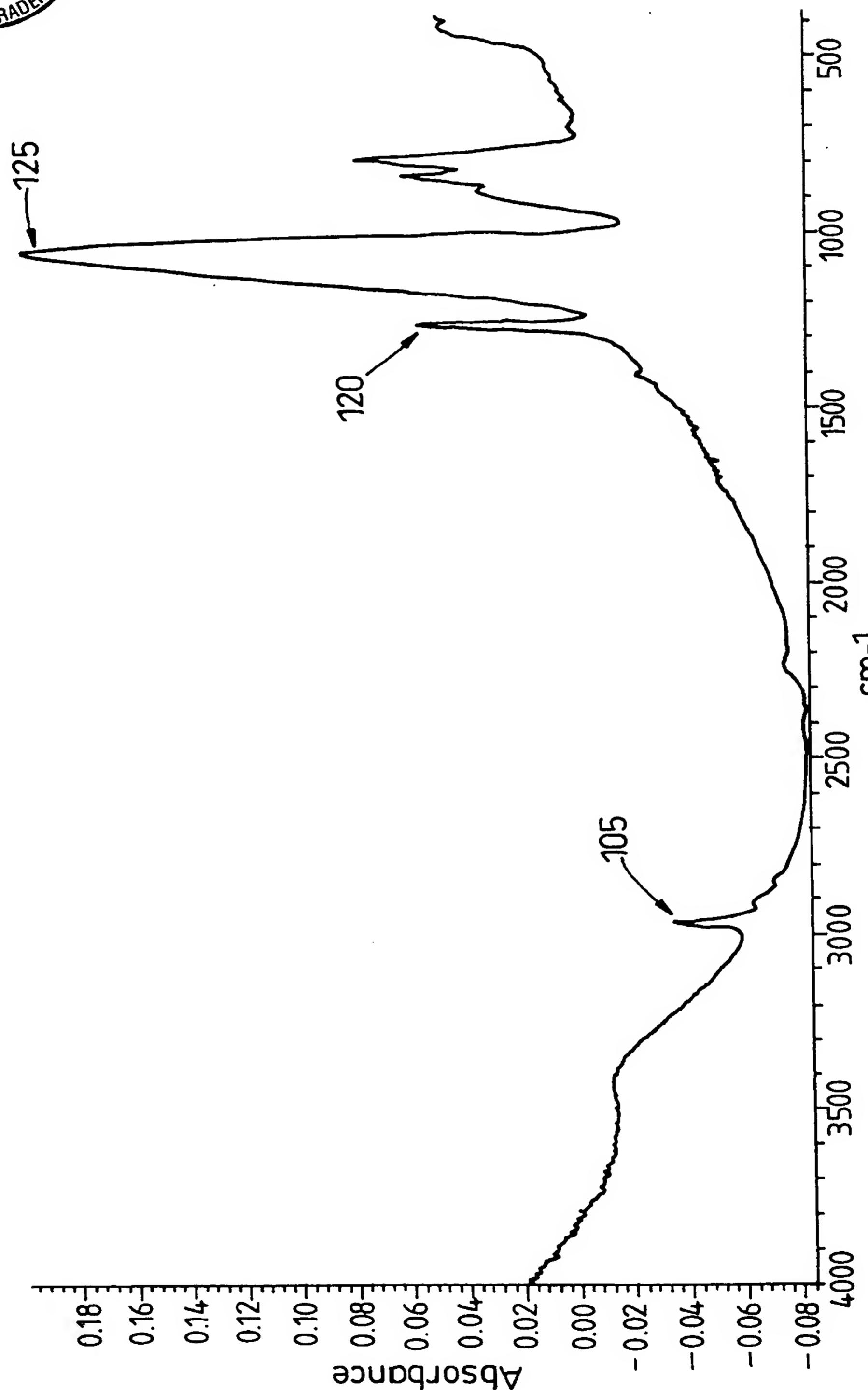


Fig. 7

"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL

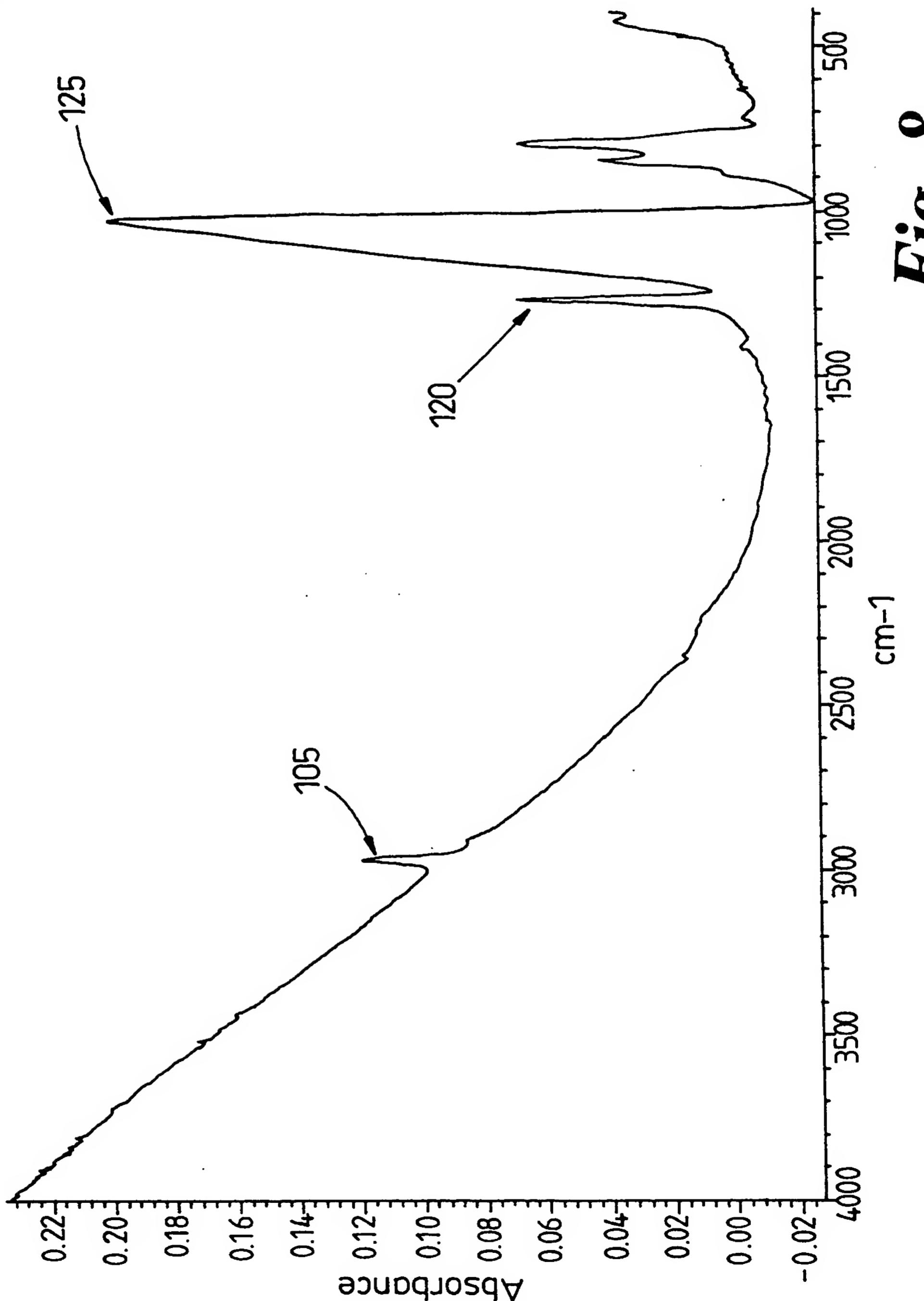


Fig. 8

"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL

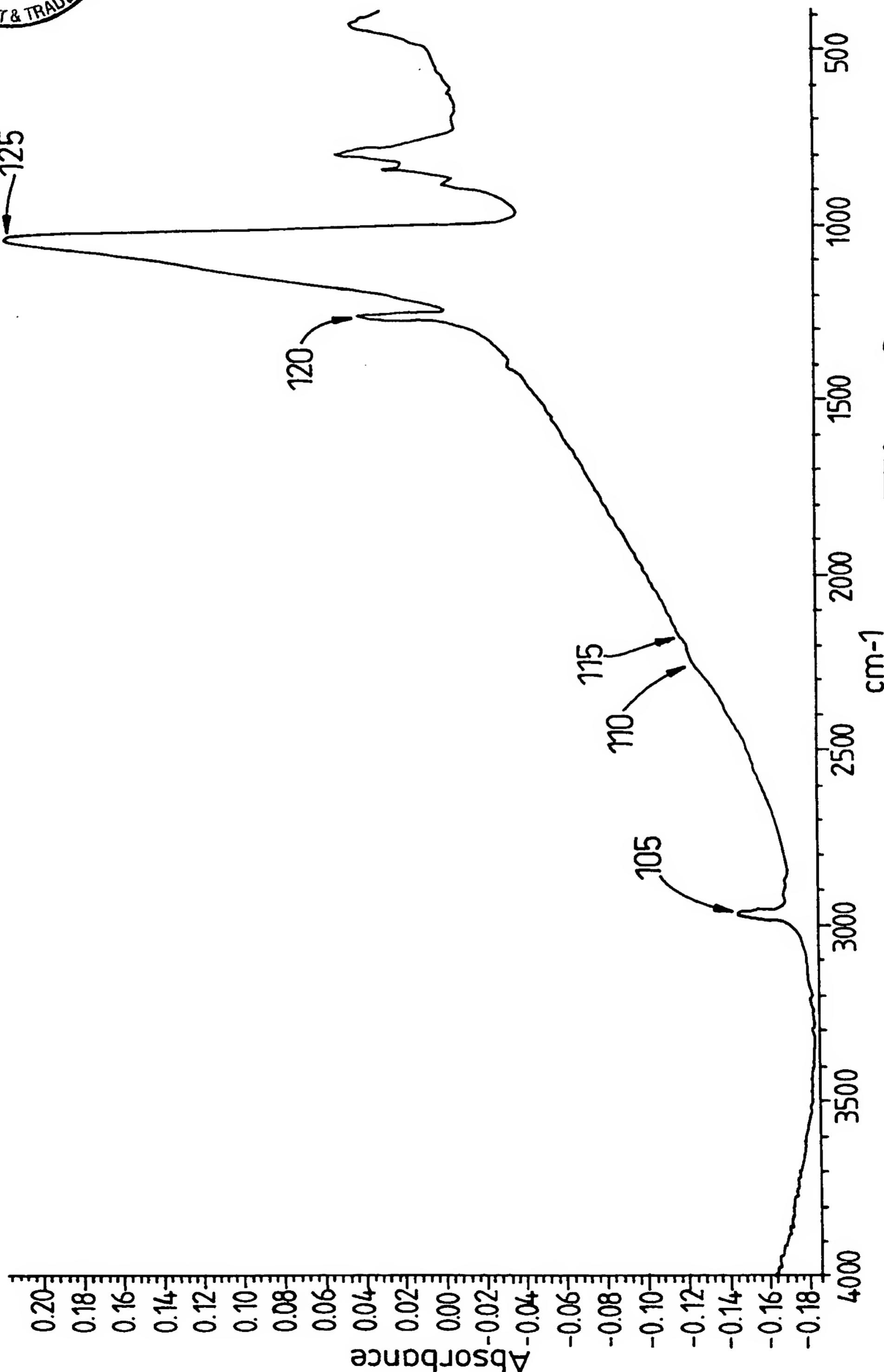
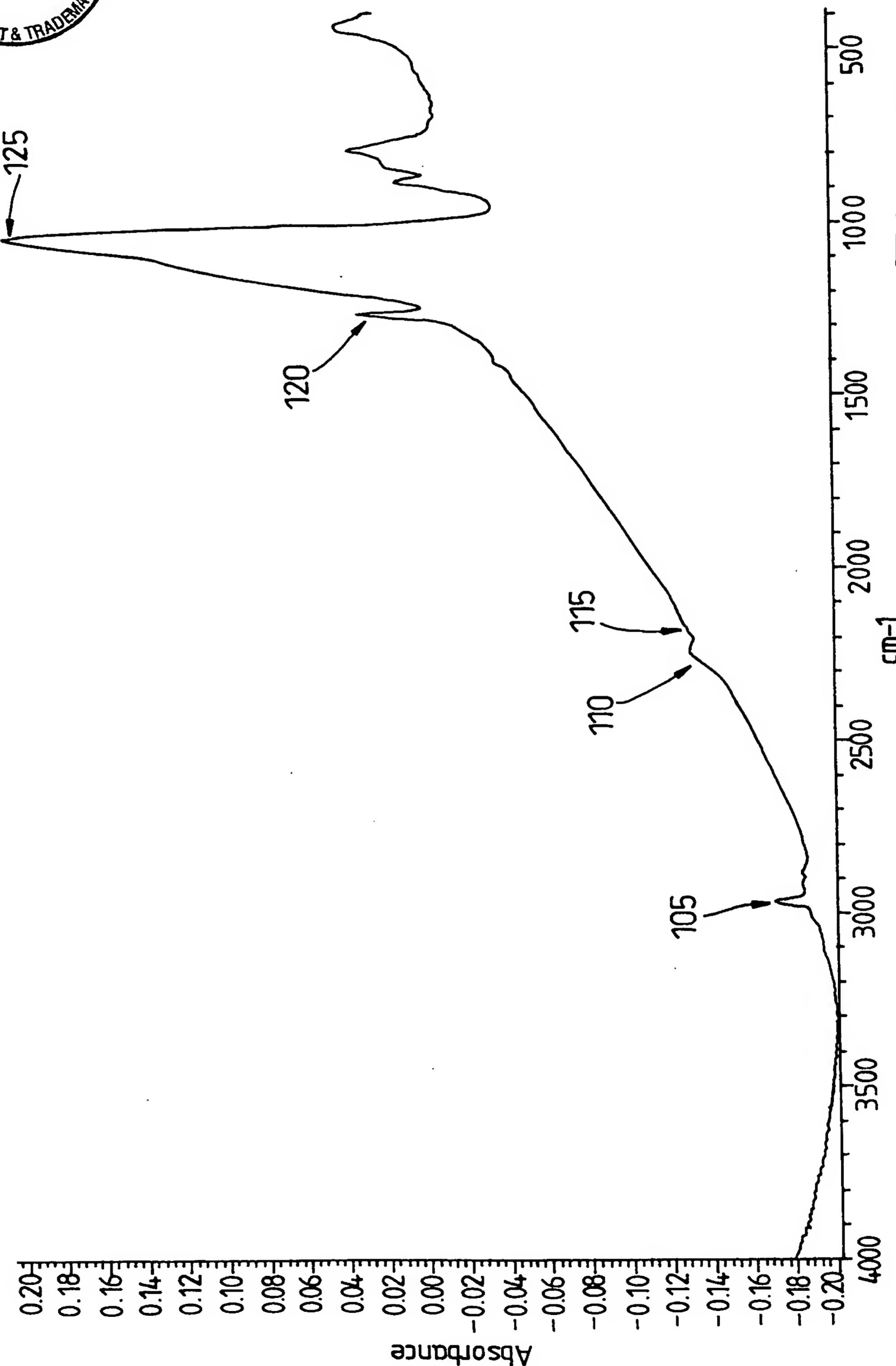


Fig. 9

"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL

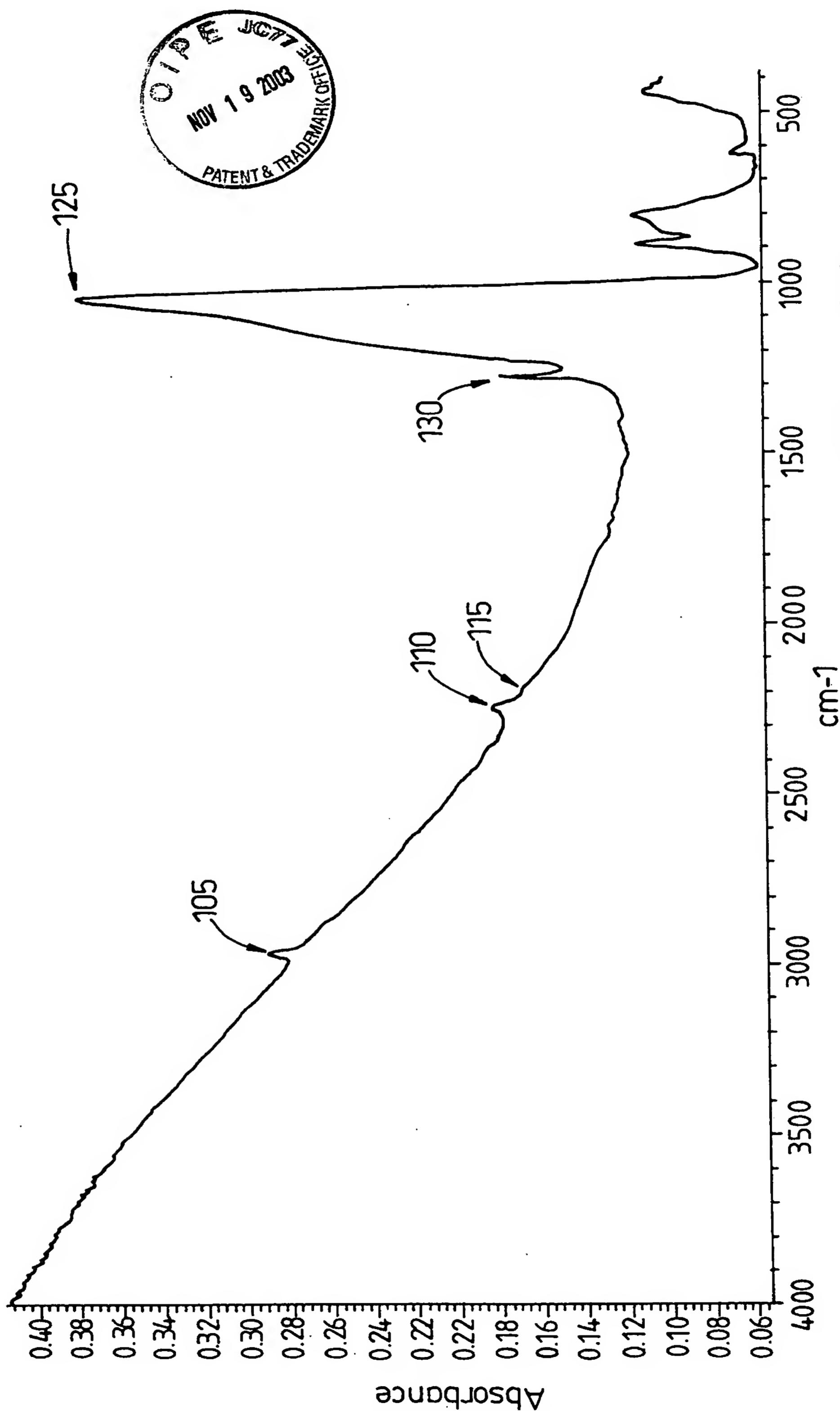
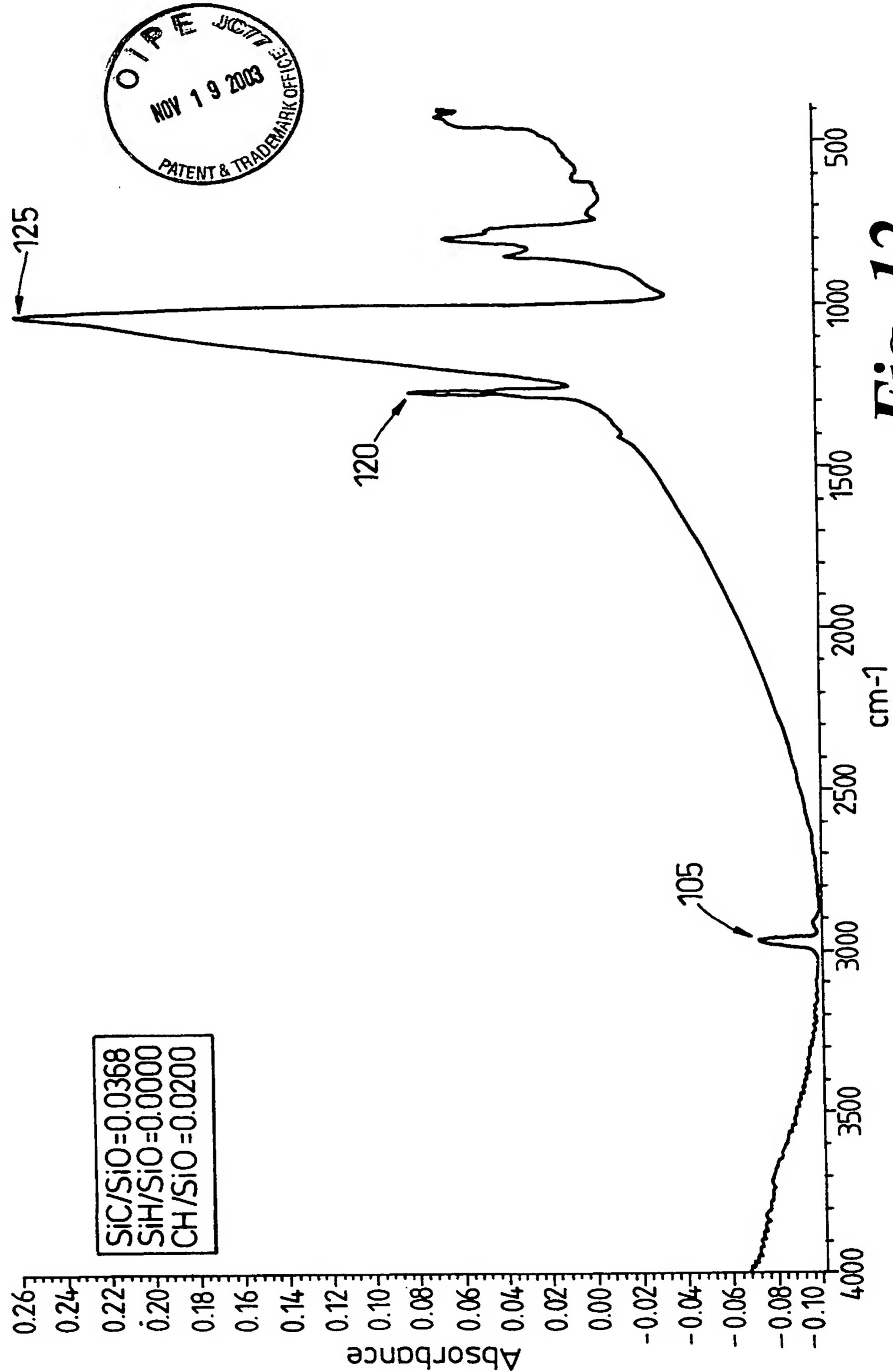
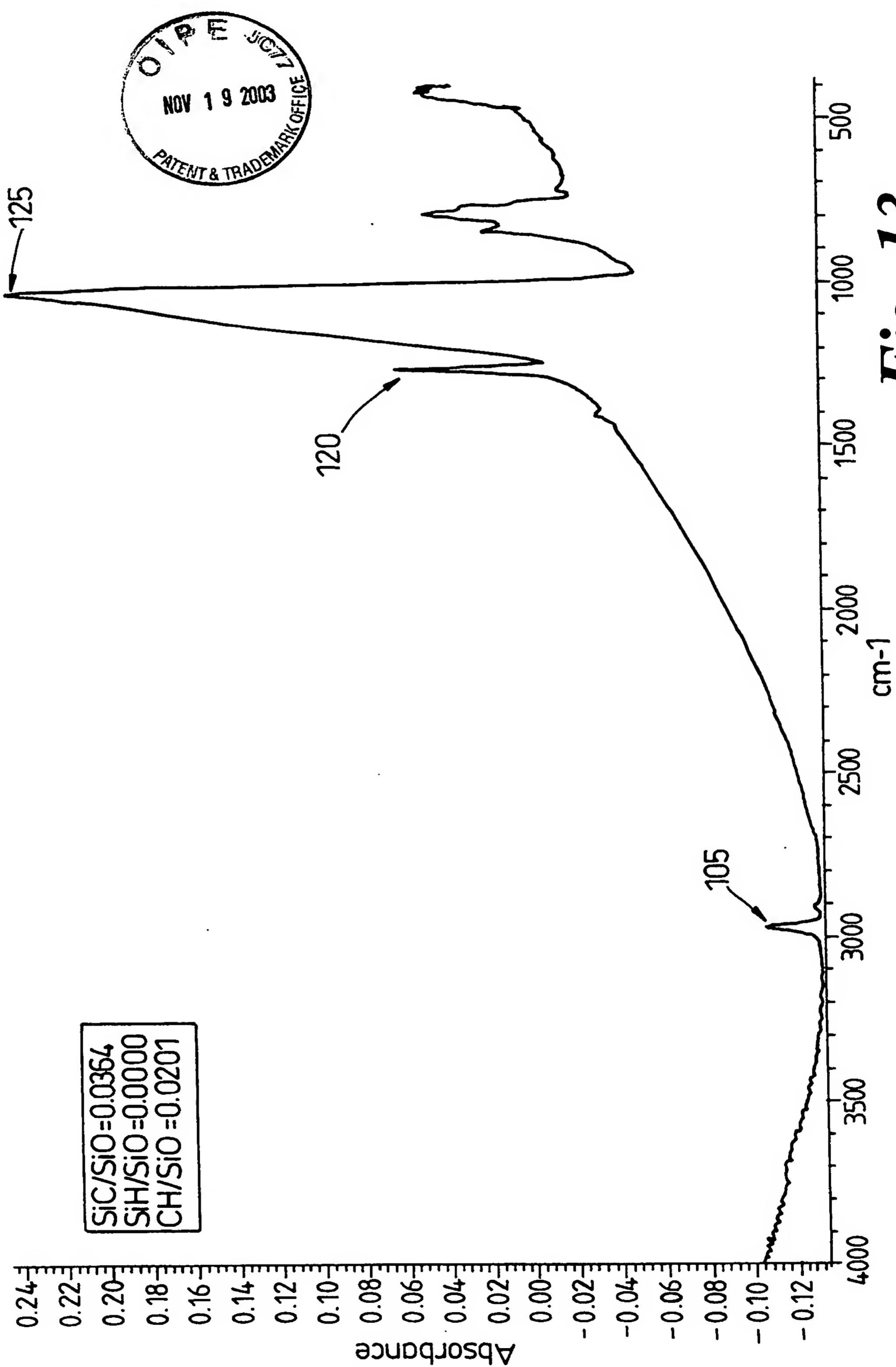


Fig. 11

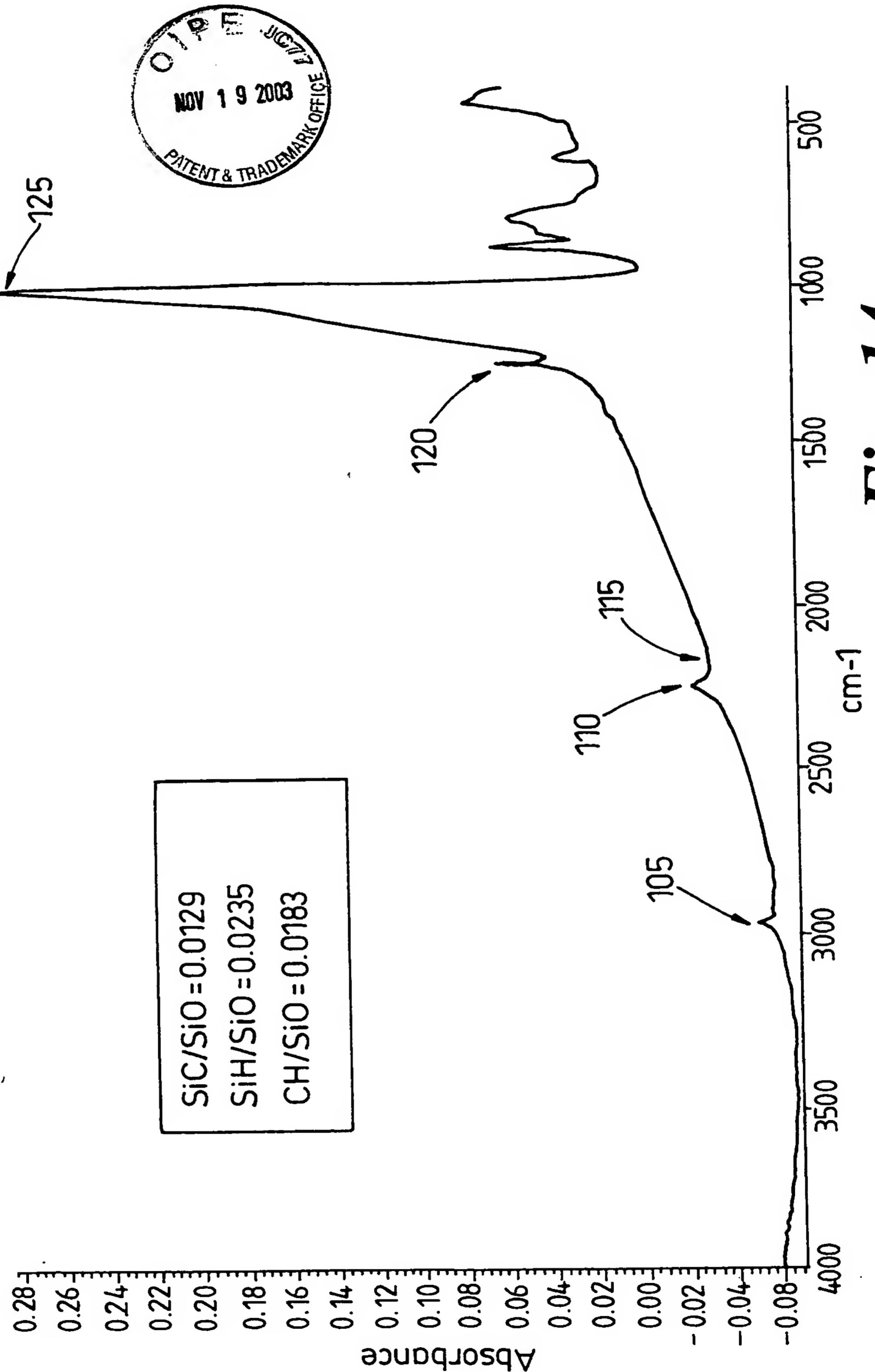
"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



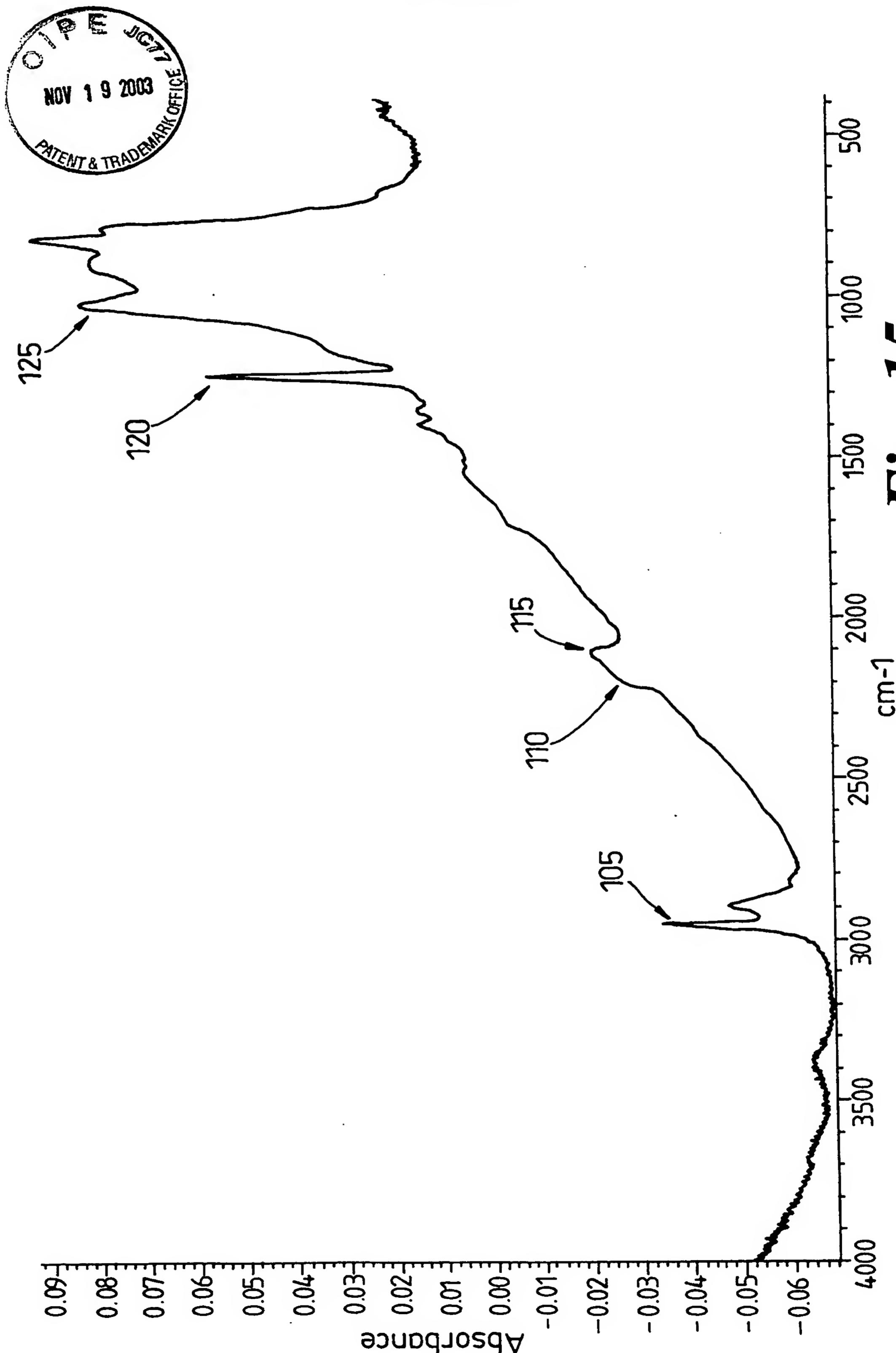
"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



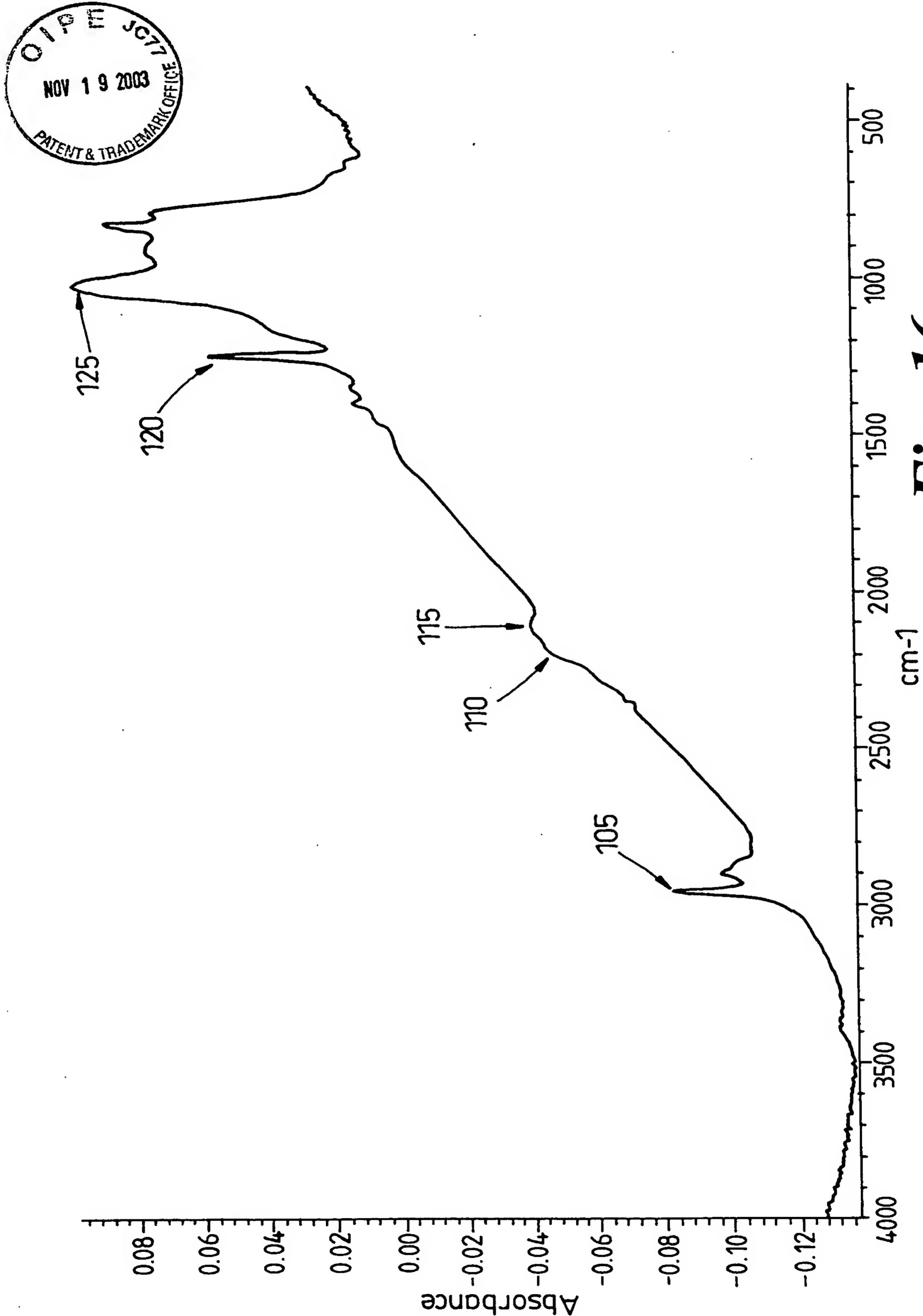
"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL

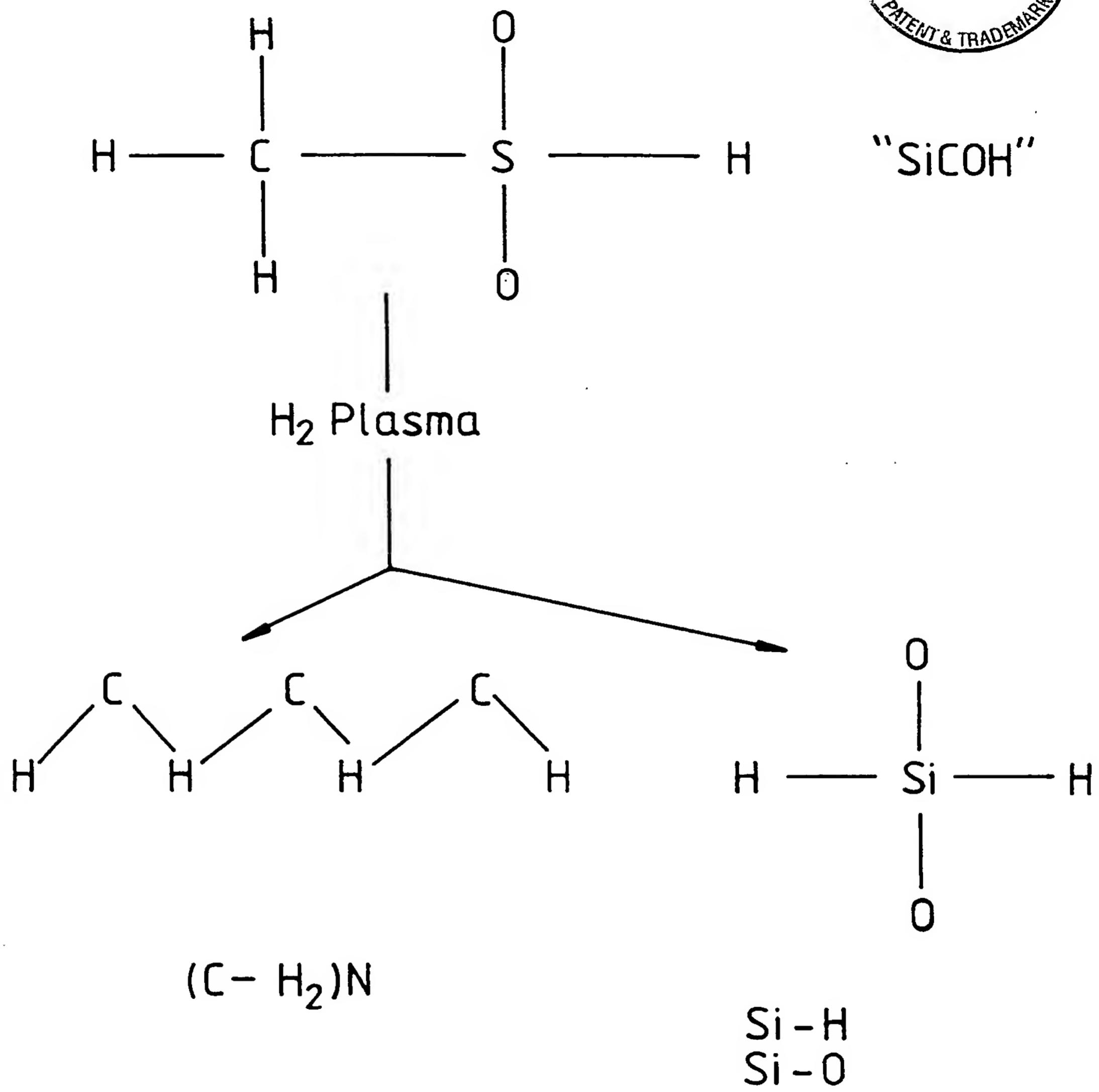


Fig. 17